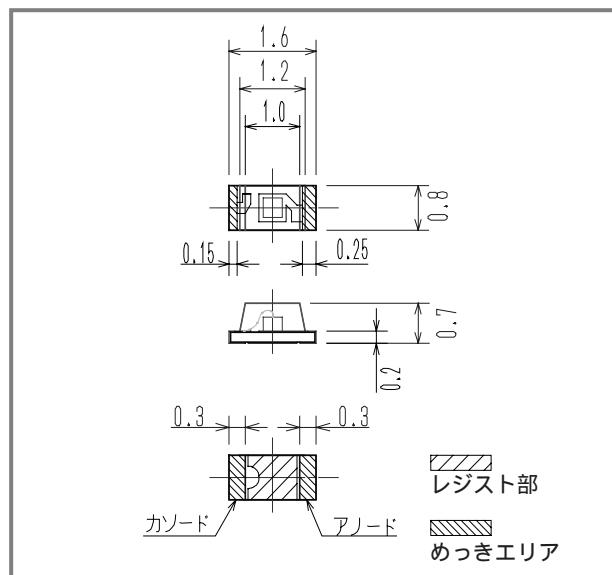


Features

- 660nm AlGaInP Red LED mounted compact package
- Transparent epoxy mold
- SMD type package

Applications

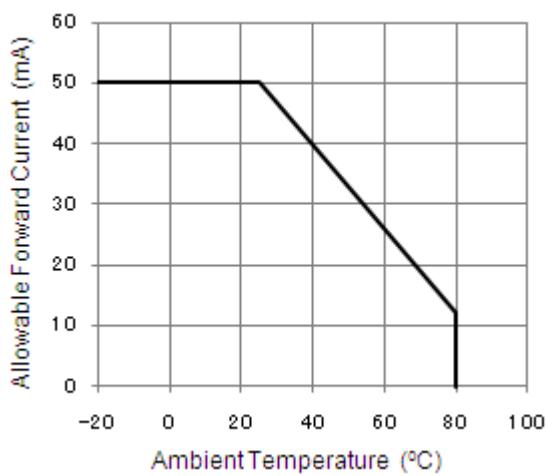
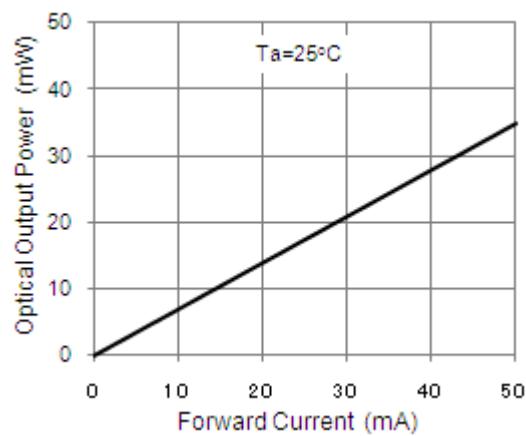
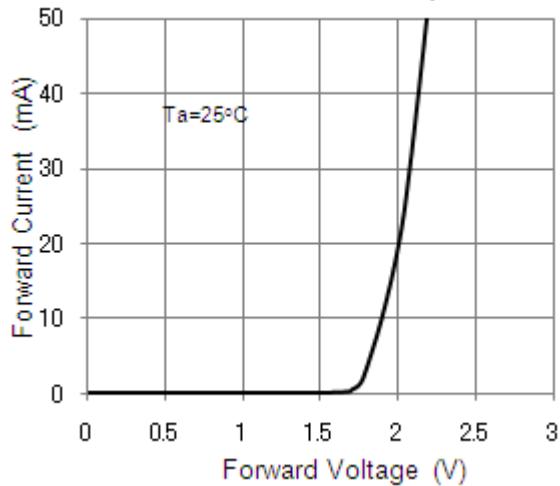
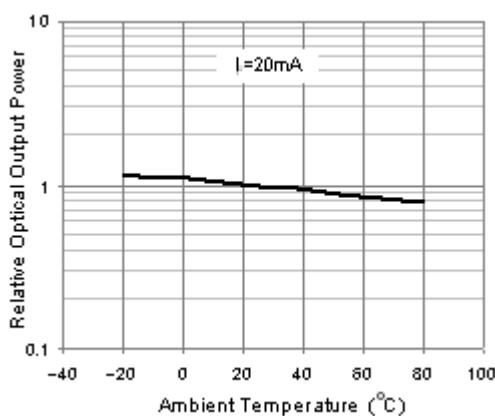
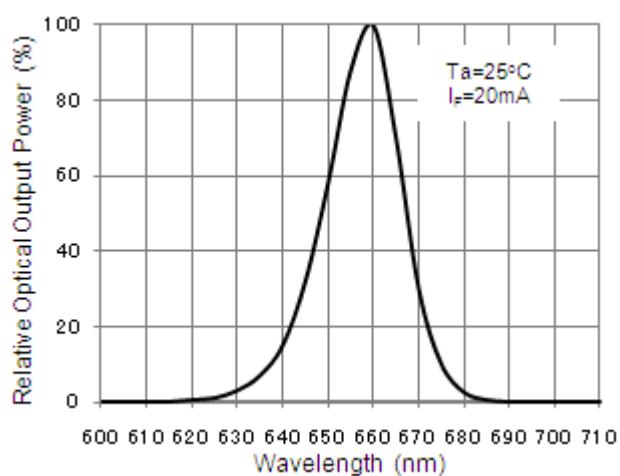
- Optical instruments

Dimensions (unit: mm)**Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit	Note
Forward current	I_F	50	mA	T _a =25°C
Peak forward current	I_{FP}	0.5	A	Pulse width=100μs, Duty ratio=0.1%
Reverse voltage	V_R	5	V	
Power dissipation	P_D	130	mW	
Operating temperature	T_{opr}	-20 to +80	°C	Avoid dew condensation
Storage temperature	T_{stg}	-25 to +100	°C	Avoid dew condensation

Electrical and Optical Characteristics (Ta=25 °C unless otherwise noted)

Parameter	Symbol	Min.	Typ.	Max	Unit	Test Conditions
Forward voltage	V_F	-	2.0	2.6	V	$I_F=20\text{mA}$
Reverse current	I_R	-	-	10	μA	$V_R=5\text{V}$
Optical output power	P_o	-	14	-	mW	$I_F=20\text{mA}$
Peak emission wavelength	λ_P	650	660	670	nm	$I_F=20\text{mA}$
Spectral bandwidth at 50%	$\Delta\lambda$	-	20	-	nm	$I_F=20\text{mA}$
Half angle	2θ		145		deg	$I_F=20\text{mA}$

Allowable Forward Current – Ambient temperature**Optical Output Power – Forward Current (Ta=25°C)****Forward Current – Forward Voltage (Ta=25°C)****Relative Optical Output Power – Ambient Temperature****Spectral Distribution (Ta=25°C, IF=20mA)****Directivity (Ta=25°C)**